2011 Pacific-Rim Laser Damage Optical Materials for High Power Lasers

Technical Program

6–9 November 2011 Blue Palace Hotel Shanghai, P.R. China

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SPIE/SIDM Pacific-Rim Laser Damage

6–9 November 2011 Blue Palace Hotel Shanghai, P.R. China

Welcome to Shanghai

On behalf of the Organizing Committee and the International Advisory Committee, we cordially welcome you to SPIE/ISOM Pacific-Rim Laser Damage 2011.

Please enjoy your week of hearing novel and fundamental advances in the fields of optical materials for high power lasers. We also hope you will take advantage of opportunities to communicate efficiently and to exchange information on new problems, solutions, and technologies in the field of laser damage as well as optical materials. We hope that this conference will contribute to an enhancement of understanding and facilitate closer collaborations among participating researchers.

We are looking forward to a productive week in Shanghai!

Conference Chair:



Jianda Shao Shanghai Institute of Optics and Fine Mechanics (China)

Cochairs:



Christopher J. Stolz Lawrence Livermore National Lab. (United States)



Koji Sugioka RIKEN (Japan)



Technical Program

Symposium Organizers

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Jianda Shao, Shanghai Institute of Optics and Fine Mechanics (China)

Conference Co-chairs:

Christopher J. Stolz, Lawrence Livermore National Lab. (USA) Koji Sugioka, RIKEN (Japan)

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Onsite Registration

Blue Palace Hotel

Sunday 6 November	13.00 to 17.00
Monday 7 November	08.00 to 16.00
Tuesday 8 November	08.00 to 16.00
Wednesday 9 NovemberF	Registration closed

Social Mixer

Sunday 6 November · 18.00 to 20.00

Be sure to come to the social mixer Sunday in the Helen Hall on the first floor of the Blue Palace Hotel to network with other conference guests. Tickets are included in the conference registration fee.

Lunches

Monday and Tuesday 7-8 November

Lunches are included on Monday and Tuesday for attendees, held in Helen Hall. Lunch tickets are furnished and will be included in the registration packet.

Welcome Reception and Dinner

Monday 7 November · 18.30 to 20.30

All registered conference attendees are invited to attend the welcome reception and dinner on Monday night. Held in the Blue Palace Hotel's Helen Hall, the event will allow time to meet others at the conference and learn more about the research going on across the Laser Damage field.



SIOM Tour and excursion to beautiful Zhouzhuang, China

Wednesday 9 November \cdot 08.00 to 17.00 The cost for the all-day tour is \$40 US

Entrance ticket, lunch, transportation and tour guides included in your registration

The conference organizers will be leading a brief tour of the SIOM laser facility followed by an excursion to Zhouzhuang, an ancient town sometimes called "Venice of China."

Located about 35 minutes from Shanghai, Zhouzhuang dates back to 1086 A.D. and features a waterway transport system of canals cutting through traditional architecture and under elegantly crafted bridges dating back to the Yuan, Qing and Ming dynasties. Many of the old houses are open to the public.

The city has been shortlisted as a possible UNESCO World Cultural Heritage Site. It has been chosen the "No. 1 Water Town of China." It is considered one of the top tourist destinations in China.

SPIE would like to express its deepest appreciation to the symposium chairs, conference chairs, program committees, session chairs, and authors who have so generously given their time and advice to make this symposium possible.

The symposium, like our other conferences and activities, would not be possible without the dedicated contribution of our participants and members. This program is based on commitments received up to the time of publication and is subject to change without notice.

Daily Schedule of Events

TIME	Sunday 6 November		
13.00 to 17.00	Registration and Material Pick-Up (Lobby, Front Office Area of Blue Palace Hotel)		
18.00 to 20.00	Social Mixer		
	Monday 7 November		
08.00 to 16.00	Registration Open		
08.15 to 08.45	Opening Remarks		
08.45 to 09.00	Photographs		
09:00 to 12.20	SESSION 1: Plenary Session		
	SESSIONS RUN CONCURRENTLY		
13.30 to 15.45	SESSION 2: Ultrafast Through CW Laser Irradiation Effects	SESSION 8: Laser Ablation and Laser Machining	
16.05 to 18.20	SESSION 3: High Laser Damage Resistant Coatings I	SESSION 9: Characterization Techniques and Measurement Protocols	
18.30 to 20.30	Welcome Reception and Dinner Tuesday 8 November		
08.00 to 16.00	Registration Open		
	SESSIONS RUN CONCURRENTLY		
08.00 to 10.00	SESSION 4: High Laser Damage Resistant Coatings II	SESSION 10: Laser Ceramics I	
10.20 to 12.20	SESSION 5: High-Power Laser Damage: UV Through	SESSION 11: Optical Glass and Fiber	
	IR I	SESSION 12: Laser Ceramics II	
		SESSION 13: Nonlinear Laser Crystal I	
13.30 to 15.15	SESSION 6: High-Power Laser Damage: UV Through IR II	SESSION 14: Nonlinear Laser Crystal II	
15.30 to 18.50	SESSION 7: Defects, Contamination, Polishing, and Surface Damage	SESSION 15: Nonlinear Laser Crystal III	
18.50 to 19.00	Closing Remarks		
	Wednesday 9 November		
08.00 to 17.00	SIOM Tour and Excursion to Zhouzhuang (Optional Tour for Attendees)		



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Pacific Rim Laser Damage 2011: Optical Materials for High Power Lasers

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Pacific Rim Laser Damage 2011: Optical Materials for High Power Lasers

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Symposium Plenary Session

Monday 7 November · 09.00 to 12.20

Session Chairs: Jianda Shao, Shanghai Institute of Optics and Fine Mechanics (China); Christopher J. Stolz, Lawrence Livermore National Lab. (USA)

Large-aperture laser resistant optics for inertial fusion lasers



Christopher J. Stolz Lawrence Livermore National Lab.(USA)

Inertial fusion lasers are actively being built and operated internationally in multiple laser programs including the National Ignition Facility at Lawerence Livermore National Laboratory (USA), Omega EP at the Laboratory for Laser Energetics (USA), Laser Megajoule (France), SGIII & SG-IV (China), Vulcan & Orion (UK), and LFEX

& GEKKO (Japan). These machines will enable exploration of scientific problems in international strategic security, basic science, and fusion energy. One of the early goals of the National Ignition Facility which was completed in 2009, centers on achieving laboratory-scale thermonuclear ignition and energy gain to demonstrate the feasibility of laser fusion as a viable source of clean, carbon-free energy. Since the 1970's materials, finishing, and coating research has focused on increasing the laser resistance of optical materials to build progressively larger and more powerful laser systems. Through partnerships with industry, low platinum Nddoped phosphate glass, potassium dihydrogen phosphate (KDP) crystals, and inclusion free fused silica are readily manufactured. Precision optical fabrication for ultraviolet laser resistance has resulted in reduction of initiating flaws by several orders of magnitude. Post processing techniques for optical surfaces and coatings such as laser conditioning, chemical etching, CO2 laser processing, and femtosecond laser machining can be used to reduce the impact of the few remaining flaws. These fabrication strategies necessary for routine megajoule operations will dictate a path to the high repetition rate operational requirements of a Laser Inertial Fusion Energy (LIFE) plant.

Biography: **Christopher Stolz** has been in the laser program at Lawrence Livermore National Laboratory (LLNL) since 1989 researching high-power laser coatings. He is currently responsible for the Optics Production group for the National Ignition Facility (NIF). Chris has served as a cochair or program chair for numerous conferences including Laser Induced Damage in Optical Materials (a.k.a. Boulder Damage Symposium) and Optical Interference Coatings. He has coauthored over 80 journal and proceeding articles and 2 book chapters.

3D microstructuring inside glass by ultrafast laser



Koji Sugioka RIKEN (Japan)

Abstract: Over the past few decades, the rapid development of ultrafast lasers has opened up new avenues for materials processing in micro and nano scales. The extremely short pulse width of the ultrafast laser minimizes the formation of heat-affected zone in the processed region, allowing for high-quality microfabrication

of soft materials as well as hard or brittle materials. In addition, the extremely high peak powers generated can induce strong absorption, even in transparent materials including glass, due to multiphoton absorption. By focusing the laser beam inside the transparent materials with moderate pulse energy, the multiphoton absorption can be confined to a region near the focus point, and thereby internal processing of transparent materials including refractive index modification, precipitation of metal atoms, fabrication of 3D microfludic structures, etc. is carried out. This paper presents 3D integration of different functions created by the ultrafast laser inside glass to fabricate microchips used for biochemical analysis. The substrate used is photosensitive glass. By the ultrafast laser direct writing, refractive index at the laser-exposed regions can be increased, resulting in formation of 3D optical waveguides. Thermal treatment after the laser irradiation grows a crystalline phase of lithium metasilicate and transforms the laser-exposed regions to visible brown color. This transformation can be used for formation of variable optical filters. Furthermore, the grown crystalline phase can be preferentially etched away by succeeding wet etching in HF solution. In this way, 3D hollow microstructures can be embedded in the glass, which can be adapted to fabricate microoptics such as mirrors and lenses as well as microfludics. These different structures and functions are applied to efficient analysis of chemical fluid samples and exploration of dynamics and functions of aquatic microorganisms and bacteria.

Biography: Koji Sugioka is a senior research scientist at RIKEN - Advanced Science Institute and a guest professor at Tokyo University of Science and Tokyo Denki University. He received B.E., M.E. and Ph.D degrees in electronics form Waseda University in 1984, 1986 and 1993, respectively. Sugioka joined RIKEN in 1986. At RIKEN, he has worked on doping, etching and deposition of semiconductors and surface modification of metals by using excimer lasers. He also studied on microfabrication of hard materials like glass by using VUV and ultrafast lasers. His current interests center on the development of advanced laser microprocessing techniques for performing surface and 3-D microstructuring of transparent materials, with applications to lab-on-a-chip, photonic and electronic devices. Sugioka has received seven awards for his research, inventions and contributions in the area of laser microprocessing. He published more than 130 articles, gave more than 80 invited talks at international conferences and about 90 invited talks at domestic conferences, and has about 30 patents or pending patents.

Progress of optical materials for highpower lasers in China



Jianda Shao

Shanghai Institute of Optics and Fine Mechanics (China)

Abstract: The talk summarizes the recent progress on the optical materials and components for the high power laser system in China. The amplifier material, Nd glass, has been developed with continuous melt. Non-

linear crystals, KDP/DKDP, have been grown with rapid and traditional growth method. Fused silica and K9 glass has been achieved high quality. Meanwhile various advanced optical fabrication processes are employed for different optical components, especially with home-made facilities and equipments. Some potential materials, for next generation high power laser system, such as large-size Ti:sapphire, Yb:crystal, laser ceramics, crystalline-glass nano-composite materials, coatings, new nonlinear crystals and so on also are evinced in this summary. The talk is to discuss how to face the challenge of the high cost-performance of these components for the laser system with an ICF driver scale.

Biography: **Jianda Shao** is a senior researcher and a deputy director of Shanghai Institute of Optics and Fine Mechanics (SIOM), Chinese Academy of Sciences (CAS). He has been being involved in research on high power laser mirrors and laser induced damage of optical materials since the 1990s, and is the chief scientist of the research group of the optical components for the high power laser system. He earned his PhD degree in optical engineering at SIOM in 1998.

Sunday-Wednesday 6-9 November 2011 • Proceedings of SPIE Vol. 8206

Pacific Rim Laser Damage: Optical Materials for High Power Lasers

Conference Chair: Jianda Shao, Shanghai Institute of Optics and Fine Mechanics (China)

Conference Co-Chairs: Christopher J. Stolz, Lawrence Livermore National Lab. (USA); Koji Sugioka, RIKEN (Japan)

Program Committee: Takahisa Jitsuno, Osaka Univ. (Japan); Norbert Kaiser, Fraunhofer-Institut für Angewandte Optik und Feinmechanik (Germany); Zunqi Lin, Shanghai Institute of Optics and Fine Mechanics (China); Richard Moncorgé, ENSICAEN (France); Detlev Ristau, Laser Zentrum Hannover e.V. (Germany); Wolfgang Rudolph, The Univ. of New Mexico (USA); Takunori Taira, Institute for Molecular Science (Japan); Zhouling Wu, Rx Technologies Co. Ltd. (China); Xiaomin Zhang, China Academy of Engineering Physics (China); Jiping Zou, Ecole Polytechnique (France)

Sunday 6 November

Registration and Material Pick-Up

Sun. 13.00 to 17.00

Blue Palace Hotel (Lobby, Front Office Area of Blue Palace Hotel)

Social Mixer

Sun. 18.00 to 20.00 Tickets for the Social Mixer will be included in the conference registration fee.

Monday 7 November

Registration Open Mon. 08.00 to 16.00

Opening Remarks Mon. 08.15 to 08.45 Session Chair: Jianda Shao,

Shanghai Institute of Optics and Fine Mechanics (China)

SESSION 1

Plenary Session

Session Chairs: Jianda Shao, Shanghai Institute of Optics and Fine Mechanics (China); Christopher J. Stolz, Lawrence Livermore National Lab. (USA)

Inertial fusion lasers are actively being built and operated internationally in multiple laser programs including the National Ignition Facility at Lawerence Livermore National Laboratory (USA), Omega EP at the Laboratory for Laser Energetics (USA), Laser Megajoule (France), SGIII & SG-IV (China), Vulcan & Orion (UK), and LFEX & GEKKO (Japan).

These machines will enable exploration of scientific problems in international strategic security, basic science, and fusion energy. One of the early goals of the National Ignition Facility which was completed in 2009, centers on achieving laboratory-scale thermonuclear ignition and energy gain to demonstrate the feasibility of laser fusion as a viable source of clean, carbon-free energy. Since the 1970's materials, finishing, and coating research has focused on increasing the laser resistance of optical materials to build progressively larger and more powerful laser systems.

Through partnerships with industry, low platinum Nd-doped phosphate glass, potassium dihydrogen phosphate (KDP) crystals, and inclusion free fused silica are readily manufactured. Precision optical fabrication for ultraviolet laser resistance has resulted in reduction of initiating flaws by several orders of magnitude. Post processing techniques for optical surfaces and coatings such as laser conditioning, chemical etching, CO_2 laser processing, and femtosecond laser machining can be used to reduce the impact of the few remaining flaws. These fabrication strategies necessary for routine megajoule operations will dictate a path to the high repetition rate operational requirements of a Laser Inertial Fusion Energy (LIFE) plant.

Coffee Break...... 10.00 to 10.20

10.20: **3D microstructuring inside glass by ultrafast laser**, Koji Sugioka, Katsumi Midorikawa, RIKEN (Japan)......[8206-02]

Ultrafast laser can perform internal processing of transparent materials including refractive index modification, precipitation of metal atoms, fabrication of 3D microfludic structures, etc due to multiphoton absorption. This paper presents 3D integration of different functions created by the ultrafast laser inside photosensitive glass to fabricate microchips used for biochemical analysis. The integrated exploration of dynamics and functions of aquatic microorganisms and bacteria.

The talk summarizes the recent progress on the optical materials and components for the high power laser system in China. The amplifier material, Nd glass, has been developed with continuous melt. Non-linear crystals, KDP/DKDP, have been grown with rapid and traditional growth method. Fused silica and K9 glass has been achieved high quality. Meanwhile various advanced optical fabrication processes are employed for different optical components, especially with home-made facilities and equipments. Some potential materials, for next generation high power laser system, such as large-size Ti:sapphire, Yb:crystal, laser ceramics, crystalline-glass nano-composite materials, coatings, new nonlinear crystals and so on also are evinced in this summary. The talk is to discuss how to face the challenge of the high cost-performance of these components for the laser system with an ICF driver scale.

Lunch Break 12.20 to 13.30

Conference 8206

Session 2 will run concurrently with Session 8.

SESSION 2

Room: Multifunctional Hall Mon. 13.30 to 15.45

Ultrafast Through CW Laser Irradiation Effects

Session Chairs: Tetsuya Makimura, Univ. of Tsukuba (Japan); Yuxin Leng, Shanghai Institute of Optics and Fine Mechanics (China)

Laser-induced fluorescence (LIF) of high-purity fused silica irradiated by ArF excimer laser is studied experimentally. LIF bands of the fused silica centered at 281 nm, 478 nm, and 650 nm are observed simultaneously. Furthermore, the angular distribution of the three fluorescence peaks is examined. Microscopic image of the laser modified fused silica indicates that scattering of the generated fluorescence by laser-induced damage sites is the main reason for the angular distribution of LIF signals. Finally, the dependence of LIF signals intensities of the fused silica on laser power densities is presented. LIF signals show a squared power density dependence, which indicates that laser-induced defects are formed mainly via two-photon absorption processes.

14.45: Surface and interface study of SiO₂ coated InP/InGaAs/InGaAsP semiconductor laser microstructures in the soft KrF laser irradiation regime, Jan J. Dubowski, Neng Liu, Sonia Blais, Univ. de Sherbrooke (Canada) . [8206-07]

In this report, we discuss the results of surface and interface study of InP/InGaAs/ InGaAs quantum well (QW) microstructures, coated with a plasma-enhancedchemical vapor-deposition (PECVD) fabricated 240-nm thick layer of SiO₂, and irradiated with a KrF excimer laser delivering up to 100 pulses at 124 and 155 mJ/cm². We have investigated both the surface morphology of the SiO₂ films deposited atop the InP layer that caps the InGaAs/InGaAsP quantum well (QW) microstructure, and the chemical composition of a laser induced layer of the altered material between SiO₂ and InP. Of particular interest to this study is an investigation of the ability to induce formation of a "defective layer" that would promote QWI without participation of impurities that, usually, contribute to the reduced performance of a device fabricated from the QWI material.

15.00: Review of femtosecond laser-induced refractive index change in transparent materials, Quan-Zhong Zhao, Geng Lin, Shanghai Institute

In this talk, three aspects of femtosecond laser induced refractive index change in transparent materials will be introduced. Firstly, the history of refractive index change in femtosecond laser induced transparent materials is reviewed. The state-of-the-art applications and the mechanisms of femtosecond laser induced refractive index change in transparent materials are discussed. Secondly, recent efforts for tuning the refractive index are introduced in femtosecond laser induced transparent materials. At last, the future trends of femtosecond laser induced refractive index change in transparent materials will be given.

15.15: Optical damage in fused silica induced by tightly focused femtosecond laser, Kangpeng Wang, Shanghai Institute of Optics and Fine

Mechanics

~100fs) has been studied.

Laser damages in optical thin films with different pulse durations from nanosecond to millisecond are investigated. The transient temperature rises of single layer film, high-reflection (HR) film, anti-reflection (AR) film and interference filter are calculated for analyzing their thermally laser damage properties. It is found that the laser field effect gradually weakens and the thermal diffusion length extends, as the laser pulse-length increases. Finally, the damage experiments of optical thin films induced by 10 ns and 1 ms lasers are carried out. The experimental results meet the thermal analytical results.

Coffee Break..... 15.45 to 16.05

SESSION 8

Room: Multifunctional Hall Mon. 13.30 to 15.00

Laser Ablation and Laser Machining

Session Chairs: Koji Sugioka, RIKEN (Japan); Zhouling Wu, Rx Technologies Co., Ltd. (China)

We have investigated ablation process of silica glass induced by X-ray irradiation. X-rays around 100 eV were generated by irradiation of Ta targets with nanosecond Nd:YAG laser light. The soft X-rays were focused on silica surfaces beyond the ablation threshold power density. Silica glass can be ablated at up to 150 nm/shot by X-ray irradiation. We oabserved ions and neutrals ejected by X-ray irradiation and found that silica surfaces are broken into atomic species by X-ray irradiation. We can conclude that Coulomb repulsion between X-ray generated ions in the surface layer are essential for X-ray ablation of silica glass.

Progress in laser processing for manufacturing of high efficiency silicon solar cells, especially the application of picosecond laser pulses for grooving and doping on crystalline silicon solar cells, has been achieved at RX Technologies, A system using this technique has been employed in production line by one of the leading manufacturers of solar cells. Efficiencies of 19.2% and 17.5% for monocrystalline silicon and polycrystalline silicon have been achieved under the condition of volume production. This result shows a great improvement, compared with results obtained from traditional manufacturing techniques.

14.15: Spatiotemporally focused femtosecond laser direct-write of microfluidic channels with a circular cross section, Qiannan Cui, Fei He,

Liao Yang, Ya Cheng, Shanghai Institute of Optics and Fine Mechanics

We report on the fabrication of hollow microfluidic channels with a circular crosssectional shape embedded in fused silica by spatiotemporally focusing the femtosecond laser beam. We show that high-aspect-ratio microfluidic channels with perfectly circular cross sections and smooth inner walls can be directly embedded in fused silica by focusing femtosecond laser pulses in both spatial and temporal domains.We demonstrate both theoretically and experimentally that the spatiotemporal focusing of femtosecond laser beam allows for the creation of a three-dimensionally symmetric spherical intensity distribution at the focal spot by use of combination of a slit beam shaping technique and a temporal focusing technique.

We demonstrate that both 3D homogeneous microchannels and large-volume hollow chambers can be fabricated inside glass by femtosecond laser direct writing in porous glass immersed in water followed by a postannealing process.

We demonstrate a new method for efficient structuring of the surface of materials by applying femtosecond NIR laser pulses simultaneously with a weak XUV beam, which leads to very strong radiation-matter interaction, bringing a dramatic increase in the surface processing speed. We present our recent experimental results of the surface nanostructuring of thin films of amorphous carbon (a-C) and PMMA deposited on bulk substrates and discuss the underlying physical mechanisms. In the case of a-C, large areas of laser-induced periodic surface structures with a spatial period of 550 nm are created, having their origin in laserinduced convective currents.

Coffee Break..... 15.00 to 15.20

Session 3 will run concurrently with Session 9.

SESSION 3

Room: Multifunctional Hall Mon. 16.05 to 18.05

High Laser Damage Resistant Coatings I

Session Chairs: Qiao Xu, Chengdu Fine Optical Engineering Research Ctr. (China); Zhanshan Wang, Tongji Univ. (China)

16.05: Subpicosecond laser breakdown in optical thin films (Invited Paper),

As an important part of almost all laser systems, optical film is so fragile that easy to damage because of temperature rise. Based on temperature field theory and thermal conduction equation, the physical model of temperature field of multiplayer films illuminated by Gaussian laser is built. By solving the Maxwell equation, the average energy flow rate of plane wave with unit intensity propagation through the films is obtained. The numerical calculation program of the temperature field of multiplayer films illuminated by 1064nm laser is built using alternating direction-implicit technique.

16.50: Heat conductivity and laser damage characteristic of particle stacking structured cellular films, Zhilin Xia, Wuhan Univ. of Technology

Aiming at particle stacking structured cellular material, a model has been established to analyze the heat conductivity. It is assumed that heat energy mainly transfers through particles and their contact points. In particle stacking structured materials, a particle contacts with twelve contiguous particles, and there is twelve heat conduction branches. The model is suit to the conditions that: the size of particles in cellular material is uniform; heat conductivity of particle skeleton is much greater than that of the clearance; all contact area between particles is approximately equal. The results show that: heat conductivity of the particle stacked cellular material is anisotropic; heat conductivity depends on that of the particle skeleton and the ratio of radius of particle contact area and particle radius.

HfO₂ single layers and HfO₂/SiO₂ high reflectors with standard 1/4 wavelength design were prepared by ion assisted deposition and ion beam sputtering. Characterization of HfO₂ single layers such as structural and optical properties, surface topography and absorption have been studied. The laser-induced damage thresholds (LIDTs) of the high reflectors with different multilayer stacks at 1064nm were tested with S-on-1 testing mode according to ISO-11254. In addition, optical properties, surface topography and absorption of these testing high reflectors have also been investigated in our experiments. All the results used to analyze the LIDTs of high reflectors have been discussed in literature.

17.20: Interface damage study of dielectric coatings by nanosecond laser

pulses, Xinbin Cheng, Zhengxiang Shen, Hongfei Jiao, Jinlong Zhang, Bin Ma,

Interfacial damage of the dielectric coatings that were prepared using electron beam evaporation process was investigated by implanting gold nano-particles into the film-film interfaces and film-substrate interfaces. The dielectric coatings were damage tested with 10-ns, 1064nm pulses. Flat bottom pits initiating from gold nano-particles were observed using Nomarski microscope and scanning electron microscope. A model based on ultraviolet radiation and plasma induced film bucking was used to interpret the damage morphologies. The dependence of damage morphologies on the coating material properties was also studied and the possible reasons for the observed dependence were discussed.

SESSION 9

Room: Multifunctional Hall Mon. 15.20 to 18.20

Characterization Techniques and Measurement Protocols

Session Chairs: Jean-Yves Natoli, Institut Fresnel (France); Christian Mühlig, Institut für Photonische Technologien e.V. (Germany)

15.20: Direct and absolute absorption measurements in optical materials and coatings by laser-induced deflection (LID) technique (Invited Paper),

Christian Mühlig, Institut für Photonische Technologien e.V. (Germany) . [8206-52]

Direct absorption measurements have been evolved into a major tool to characterize optical materials and coatings. Characterizing the absorption of optical materials and coatings is a central task for manufacturers to ensure stability in the production process, to verify functionalities and to understand possible performance changes and limitations, e.g. thermal lens generation, depolarization, during their use in high power laser applications. Here, the laser induced deflection (LID) technique, its absolute calibration, and several measurement strategies are introduced for sensitive direct absorption measurements. Various experimental results are presented covering a wide range from deep UV to IR applications. A new strategy is introduced allowing a significant increase in the sensitivity for materials with a weak photothermal response.

15.50: Relevance of the choice of diagnostic methods to investigate laser damage resistance in optical material (*Invited Paper*), Jean-Yves Natoli,

Mireille Commandré, Laurent Gallais, Frank R. Wagner, Institut Fresnel

Laser damage in optical material in nanosecond regime is widely attributed to local precursor centers. The weakness of knowledge on sizes, densities and natures of precursors, let think that the choice of the diagnostic method has to be adapted to each situation of irradiation. For LIDT determination, destructive methods are usually involved (full size test, raster scan method and statistic approach). This multi-scale approaches give relevant information on material properties. In order to investigate the laser damage initiation mechanisms, fatigue or conditioning effects, non destructive diagnostics as fluorescence and photohermal deflexion appear necessary to highlight modifications before breakdown. To illustrate the purpose, examples on non linear crystals and coatings will be shown.

16.20: High reflectivity scan measurment on large-aperture laser optics with OF-CRD instrument, Lifeng Gao, Bincheng Li, Institute of Optics and

related features. The experimental results show that the ability of this algorithm is better than the traditional algorithm in the aspect of image denoising. 16.50: **Measurement of losses in optical components using filtered optical feedback cavity ring down technique**, Zhechao Qu, Bincheng Li, Yanling Han,

A filtered optical feedback cavity ring down (FOF-CRD) technique employing a continuous wave diode laser is employed to measure the total optical losses, absorption and scattering in optical components with arbitrary thickness. The FOF from the ring down cavity (RDC) is re-injected into the oscillator cavity of the laser, and the coupling efficiency of the laser into the RDC is significantly enhanced. An optical component having optically flat parallel surfaces is inserted exactly normal to the light beam in the RDC. The optical losses in the component are obtained from the change in the decay time of the light in the RDC containing the component with respect to that of the empty RDC. The measurement results for different samples are good agreement with conventional laser calorimetry data. The experimental results have demonstrated the FOF-CRD technique is very simple, inexpensive and fast for measuring optical losses of optical components used in high-power laser system.

Session 3 will run concurrently with Session 9.

SESSION 3 (Continued)

Room: Multifunctional Hall..... Mon. 16.05 to 18.05

The coupling effect of multilayer mirrors under simultaneous irradiation by 355 nm laser and 1064 nm laser are investigated. A critical fluence of 1064 nm laser is found. When the fluence is lower than it, 1064 nm laser does not contribute to 355 nm laser induced damage, otherwise, the LIDT in 355 nm laser decreases with the growth of 1064 nm laser fluence and the coupling efficiency is about 5%. Damage morphologies are also studied to explore the damage mechanism at respective wavelength. Under simultaneous illumination, the sensitive defects are still the precursors, but the damages were more catastrophic compared with the damage induced by 355 nm or 1064 nm laser alone. The possible explanation is also discussed.

17.50: **The study on high laser damage threshold biochamatic coatings fabrication**, Feng Pan, Chengdu Fine Optical Engineering Research Ctr.

SESSION 9 (Continued)

Room: Multifunctional Hall Mon. 15.20 to 18.20

Fluorescence microsopy is a useful tool to image defect nanostructures in the bulk of dielectric materials. The application of microcopy with KrF laser induced fluorescence on optics to detect the damage of opticcal film was explore. A fluorescence image system was built that incorporated in-situ damage testing capabilities. The experimental results was checked under an ex-situ Normaski microscope.

17.20: Extrapolation from small area test of laser-induced damage to the

Due to the limits of experimental conditions the results of the small area damage testing cannot represent the performance of the material illuminated by large scale high power laser whose typical scale is usually a few decimeters in diameter. By use of statistical approach, extrapolation from small area test of laser induced damage to the large area is provided, and damage probability curve is obtained to describe the characteristics of large-scale material. Furthermore, the Monte Carlo simulation is also given to verify the reliability of the extrapolation results. The above-mentioned revised approach can be suitable for large scale material.

In chirped pulse amplification laser systems, the damage threshold of the final grating in the pulse compressor may ultimately limit the energy output. Here we propose a novel measurement, by which the exact correlation between local fluence and local damage characteristics would be established. This method , though online monitoring, collecting the near-field intensity distribution of a cm-sized beam spot and its corresponding raster damage image, also including a series of image post-processing, does not strictly require the spatial uniformity of the beam. Furthermore, the damage densities versus fluence would be extracted with one shot.

17.50: **Influence caused by spacing and angle misalignment of the 4f setup on the femtosecond pulse temporal properties**, Yongming Nie, Junli Qi, Jiankun Yang, Wenhua Hu, Xiujian Li, National Univ. of Defense Technology

Based on zero-dispersion 4f ultra-fast pulse shaping system, the relation between the resolution and the mismatched spacing of the system components was analyzed in theory. The effect of mismatched spacing and angle on the system efficiency was discussed. Moreover, pulse temporal expansion caused by the misalignment was analyzed in detail. The experimental results indicate that lens misalignment will broaden the pulse temporal width and the influence of the first grating was symmetrical with the influence of the second one. When the second grater. The influence on system's efficiency of angle misalignment is more serious than spacing misalignment. If 600 lines per millimeter grating and lens with 30 cm focal length were used, when the angle misalignment was smaller than 9 degree and the spacing misalignment was smaller than 0.5 cm, the changing of system's efficiency and the pulse width were both smaller than 5%.

18.05: The simple theoretical analysis of optical absorption coefficient (OAC) in optical nanomaterials in the presence of laser, Subhamoy Singha

I have given away on the origin of operator algebra that the optical absorption coefficient (OAC) in optical nano compounds, whose $(E - \vec{k})$ energy band structures are defined by the three band model of Kane, is proportional to square root of $((\omega)^2 E_q^2$) (ω and E_q are the energy of incident radiation and band-gap respectively) instead of $((\omega) - E_q)$) as glowing known in the content. The optical absorption coefficient (OAC) of optoelectronic materials within the frame work of the three band model of Kane in the presence of an laser for modified photon energy (ω_1) below and above the band gap (E_q) respectively. The optical matrix element (OME) depends on the electron wave vector $k = 2\pi/\lambda$ and this practical aspect has been incorporated in the present analysis. It has been invent taking Hg1-xCdxTe, In1-xGaxAsyP1-y, InAs and InSb lattice matched to InP as examples of optoelectronic nano materials for mathematical computations that, for the modified energy (ω_1) below the band gap, the exhibits an exponential fall off with the laser and the photon energy in that order. For the opposite inequality, the OAC oscillates with the modified photon energy without the consideration of the Wannier-Stark levels (WSL), which generally exists in a band due to the presence of a laser. In both the cases, the OAC exhibits the singularity when the incident photon energy $(\boldsymbol{\omega}_0)$ tends to E_q and the magnitude of the OAC depends to a large extent on the numerical values of the energy band constants of the said nano materials.

Welcome Reception and Dinner

Mon. 18.30 to 20.30

All registered conference attendees are invited to attend the Welcome Reception and Dinner. A ticket will be included in the conference registration fee.

Tuesday 8 November

Registration Open08.00 to 16.00

Session 4 will run concurrently with Session 10.

SESSION 4

Room: Multifunctional Hall.....Tues. 08.00 to 10.00

High Laser Damage Resistant Coatings II

Session Chairs: Wolfgang Rudolph, The Univ. of New Mexico (USA); Hongbo He, Shanghai Institute of Optics and Fine Mechanics (China)

The performance of meter-scale multi-layer dielectric mirrors is fluence-limited by growing damage sites. We combine finite-difference time-domain method with fentosecond laser machining to determine optimal mitigation geometries that improve the laser damage resistance of mirrors by replacing a damage site. The field intensification induced by the mitigation pit is dependent on the polarization and the angle of incidence (AOI) and an optimal mitigation structure can also be achieved by matching the cone angle of the structure with the AOI. Damage testing shows that these mitigation features created by femtosecond laser machining can double the fluence-handling capability of multilayer mirror coatings.

08.30: Multiple pulse laser-induced damage investigation of 1064nm reflection coatings, Zhichao Liu, Jin Luo, Songlin Chen, Feng Pan, Chengdu

Damage properties of the hafnia-silica reflection coatings under multi-pulse laser irradiation in vacuum were studied in this work. The behaviors of LIDT against increases in shot number were discussed by S/1 test. Results indicate that there are two dominant damage morphologies on coatings surface, scalds and delaminates respectively. Scalds have a lower LIDT but maintaining stable with shot number increasing. However, the LIDT of delaminates shows an exponential decay behavior at higher fluence level. Finite element method was employed to simulate the thermal accumulation process. Finally, a simple function based on simulation result for fitting the decay law of LIDT was discussed.

Abstract: Nb₂O₅ thin films at various substrate bias voltages were deposited by pulsed DC reactive magnetron sputtering of a metallic Nb target in a pure oxygen atmosphere. The characteristics of the films have been studied. Results indicate that substrate bias voltage has significant influence on the laser resistance of Niobium oxides films which can be contributed to the variation of stress in Nb₂O₅ films. The maximum laser induced damage threshold (LIDT) of 28.8 J/cm² was obtained for the film deposited at substrate bias voltage of -60V.

09.00: Laser damage properties of thin films grown by atomic layer

Atomic layer deposition (ALD) has been used to deposit films at different temperature on different substrate using organic and inorganic precursors. The LIDT of samples was measured by a damage test system. Damage morphology was studied under Normaski Differential Interference Contrast-Microscope, and further checked under the Atomic-Force-Microscope. The results show deposition temperature affects the deposition rate, the thin film microstructure and further influences the LIDT of the thin films. Organic residual affects the LIDT of the films. The film LIDTs can further increased when the technics condition were optimized. Therefore, ALD is a promising method for high power laser system.

Micro-defect is one of key limited factors in improving laser induced damage threshold (LIDT) of thin films. In this paper, thin films were prepared by e-beam evaporation with different HfO₂ material and pre-melting process, respectively. The experiments results indicate that some impurity elements play important roles on LIDT of the samples. Well pre-melting process is necessary to keep the deposition stable, which also could be reducing micro-defect density in thin films.

SESSION 10

Room: Multifunctional Hall Tues. 08.00 to 10.00

Laser Ceramics I

Session Chairs: Richard Moncorgé, ENSICAEN (France); Jun Xu, Shanghai Institute of Optics and Fine Mechanics (China)

08.00: The transparent ceramics in SICCAS (Invited Paper), Yubai Pan,

09.00: Investigation on the visible and infrared emission properties of Tm: Y_2O_3 transparent ceramic, Qing Yi, Shengming Zhou, Shanghai Institute of

09.15: Preparation of Tb₃Al₅O₁₂ (TAG) transparent ceramics for potential magneto-optical applications in high-power laser systems, Shengming

Zhou, Shanghai Institute of Optics and Fine Mechanics (China) [8206-64]

The relationship between light scattering and microstructure, especially pores distribution, was studied in laser transparent ceramics. Specimens with different transmittance value were prepared by the solid-state reaction and the vacuum-sintering technique. Light scattering defects were studied using UV-Vis spectrophotometer and micromechanism was characterized via high magnification optical microscope. The relation curve of transmittance and pores ratio was obtained. It makes judging transmittance or scattering of transparent ceramics from pores ratio possible.

Session 4 will run concurrently with Session 10.

SESSION 4 (Continued)

Room: Multifunctional Hall.....Tues. 08.00 to 10.00

The mirrors for broad bandwidth 800nm pulse compression grating were fabricated with optimized parameters by electron beam evaporation using three different kinds of materials (Ta₂O₅/SiO₂/HfO₂), which have more than 99% reflectance with band width larger than 200 nm around the center wavelength of 800 nm and high transmission at the exposure wavelength of 413 nm. Laser induced damage (LID) behaviors of the mirrors were investigated. It was found that the laser induced damage threshold (LIDT) of the samples can reach 1.0J/cm² and 2.0J/cm² (57 degrees, TE mode) at pulse width of 50fs and 120fs, respectively.

09.45: Enhanced laser-induced damage threshold of antireflective porous glasses, Ying Du, Yunxia Jin, Hongbo He, Lei Yan, Fanyu Kong, Heyuan Guan,

Porous nanostructures on glasses were produced by chemical treatment for antireflection and high laser-induced damage threshold (LIDT) purpose. Herein, the laser-damage properties of porous nanostructures on BK7 glasses which were manufactured in neutral solution were investigated. The porous glasses have transmittance above 99.7% and average LIDT by 12ns 1.064µm pulses of 58J/cm², by 10ns 0.532µm pulses of 20 J/cm² and by 8ns 0.355µm pulses of 12 J/cm². The treated surfaces with different experiment condition have variational LIDT compared with untreated substrates. Detailed mechanisms for the LIDT enhancement are discussed.

Coffee Break...... 10.00 to 10.20

Session 5 will run concurrently with Sessions 11, 12, 13.

SESSION 5

Room: Multifunctional Hall Tues. 10.20 to 12.20

High-Power Laser Damage: UV Through IR I

Session Chairs: Jiping Zou, Ecole Polytechnique (France); Ya Cheng, Shanghai Institute of Optics and Fine Mechanics (China)

10.20: Research progress in laser-induced damage of optics for SG laser

The SG-III laser facility is a large aperture neodymium-glass based high-power solid state laser, and is composed of 48 beams in 6 bundles to provide laser energy output of 150-200kJ (3ω) for square pulse of 3ns. The 48 beams of the SG-III have a right section of $40\times40~cm^2$ and equipped with about 40 optical parts of various types: laser slabs, lenses, mirrors, diffractive optics. All of them have to sustain high fluence inducd by laser beam. It is a real technological and economical challenge to construct, operate and maintain such a large laser facility under high laser fluence ($4J/cm^2$, 351nm, 3ns). Laser-induced damage of optics is a main concern. This presentation gives an overview of this activity we have encountered and details the main recent development realized.

10.50: Laser damage performance of pulse compressor grating,

 SESSION 11

Room: Multifunctional Hall Tues. 10.20 to 10.50

Optical Glass and Fiber

Session Chairs: Mauro Tonelli, Univ. di Pisa (Italy); Satoshi Wada, RIKEN (Japan)

10.20: Er-doped fiber lasers operating at pulse duration from ps to ns

SESSION 12

Room: Multifunctional Hall.....Tues. 10.50 to 11.20

Laser Ceramics II

Session Chairs: Mauro Tonelli, Univ. di Pisa (Italy); Satoshi Wada, RIKEN (Japan)

10.50: **Composite YAG/Nd:YAG transparent ceramics for high-power lasers**, Jiang Li, Wenbin Liu, Benxue Jiang, Xuewei Ba, Yiqiang Shen, Guoxi Jin, Yubai Pan, Xiqi Feng, Jingkun Guo, Shanghai Institute of Ceramics (China)... [8206-68]

Compared with laser single crystal, one of the prominent advantages of laser ceramics is ease of achieving composite structure. This advantage provides more freedom in the design of laser systems, especially in the high power lasers. In the present work, composite YAG/Nd:YAG transparent ceramics were fabricated by solid-state reaction method using commercial--Al₂O₃, Y₂O₃ and Nd₂O₃ powders as starting materials. The microstructure and optical properties of the composite laser ceramics were also investigated. High quality composite YAG/Nd:YAG transparent ceramics might be a potential gain media for high power laser.

Session 5 will run concurrently with Sessions 11, 12, 13.

SESSION 5 (Continued)

Room: Multifunctional Hall Tues. 10.20 to 12.20

Laser damage performance of pulse compressor grating (PCG) is investigated with the method of rigorous coupled wave method. The factors such as groove depth, duty cycle, incident angle, residual thickness are researched in details to obtain optimized PCG with high laser induced damage performance. Simulation results show that the structure show great effect on laser induced damage of PCG.

11.05: Comparative investigation of laser-induced damage on K9 and fused silica under 1064nm nanosecond laser irradiation, Hongjie Liu, China

at the same experimental condition with 1064nm nanosecond laser. The initial damage threshold, the damage growth threshold and the damage growth laws of two optics are investigated comparatively. The results show that the initial damage threshold of the two glass is the same, the damage area growth both obey the exponential increase rule and that the damage depth growth obey the linear increase rule. However, there is apparent difference in the rule of damage growth coefficient for K9 glass. This can be explained by the difference of the material's damage morphology, optical absorption, residual stress near damage site and emission spectra of damage area of the two optics. The research is very important to cohose transparent optical material applied in high power laser.

SG-99 simulator is adopted to simulating laser damage mitigation pit induced beam modulation at the wavelength of 1064nm, 532nm and 355nm in fused silica. It is showed that when mitigation pit is on the front surface, the most intense modulation distance is about 5cm to the front surface. Along with increase of distance, amplitude of modulation fluctuation decreases gradually and is prone to a constant when transmission distance is above 30cm.

11.35: Research for ultra-short pulse ablation of dielectric film mirror,

Zhimin Xiong, Youen Jiang, Xiaochao Wang, Panzheng Zhang, Fan Wei, Xuechun Li, Shanghai Institute of Optics and Fine Mechanics (China) [8206-29]

By comparing the damage morphology and damage resistant threshold of the ablation pits at different pulses width, it show that it was superior to use ultra-short pulse to repair multi-layers optical components, and the shorter pulse width has been used, the better results will be got. Furthermore, the finite-difference time-domain method was used to simulate the electric-field intensification within the multilayer films, and the system parameters were optimized, including pulse width, energy, frequency, scanning speed, etc. Based on the testing of damage resistant and optical field distribution experiments, the most optimization parameters and the perfect damage morphology were determined.

11.50: **Incubation effect of laser-induced surface damage of HfO₂/SiO₂ HR coating in the femto-nanosecond region**, Shunli Chen, Yuanan Zhao, Fanyu Kong, Dawei Li, Hongbo He, Jianda Shao, Shanghai Institute of Optics and Fine

This paper is devoted to a long-term investigation into the nature of incubation effect of multilayer dielectric HR coatings. Accumulated damage behaviors of HfO₂/SiO₂ coatings for 800nm, 1053nm, and 1064nm, were investigated by ultrashort pulse, short pulse, and long pulse lasers, respectively. Incubation effect was found to be a universal phenomenon for HfO₂/SiO₂ coatings irradiating by the femto-nanosecond lasers. Besides, typical damage morphologies revealed intrinsic and determinate performance in the fs regime, while showing clear features of inclusion/defect-induced damage in the ns regime, and displaying the characteristics of the first two in the ps regime.

12.05: Novel subwavelength microstructures for antireflection application,

Lunch Break 12.20 to 13.30

SESSION 13

Room: Multifunctional Hall Tues. 11.20 to 12.05

Nonlinear Laser Crystal I

Session Chairs: Mauro Tonelli, Univ. di Pisa (Italy); Satoshi Wada, RIKEN (Japan)

In this study, the weak absorption coefficients of the flux-grown KTP crystals with titanium from TiO₂, TiCl₄ and Ti(OC₄H₉)₄ and the hydrothermal-grown KTP crystal have been measured at 1064nm and 532nm by Photothermal commonpath interferometer. The values of four samples are 100pm•cm⁻¹, 800pm•cm⁻¹, 45ppm•cm⁻¹, 20pm•cm⁻¹ at 1064nm and 2.6×10⁴ppm•cm⁻¹, 800pm•cm⁻¹, 1.2×10⁴ppm•cm⁻¹, 3.0×10²ppm•cm⁻¹ at 532nm. The results showed that the weak absorption coefficients of the flux-grown KTP with titanium from Ti(OC₄H₉)₄ and the hydrothermal-grown KTP were low values at 1064nm. In addition, the weak absorption coefficient of the hydrothermal-grown KTP was at least 2 orders of magnitudes lower than that of the flux-grown KTP at 532nm. From the results, we have concluded that the KTP grown by titanium from Ti(OC₄H₉)₄ represented a better quality than the other two flux-grown KTP crystals. The quality of the hydrothermal-grown KTP.

11.35: Structural and spectral investigations on heavily Er³⁺-doped ATaO₄(A=Sc,Y,Gd,Lu) polycrystalline powders, Pengyu Zhou, Qingli Zhang,

Dunlu Sun, Shaotang Yin, Anhui Institute of Optics and Fine Mechanics

11.50: Studies on the spectroscopic properties of Nd/Na-codoped CaF_2 $\,$

single crystal, Qingguo Wang, Shanghai Institute of Ceramics (China). [8206-72] High optical quality Nd/Na co-doped CaF₂ crystal was grown by Modified Bridgman Method. The UV-VIR-NIR absorption spectra and the near-infrared emission spectra were measured and analysed in the framework of the Judd-Ofelt. The stimulated emission cross-section of 1.25×10^{-20} cm² at 1041 nm was calculated using F-L equation. The 4F3/2 luminescence lifetimes with 3.24 ms at 300K were determined from luminescence decay curves, indicating high quantum efficiency in Nd/Na co-doped CaF₂ crystal. All the results showed that Nd/Na codoped CaF₂ crystal would be a promising gain media in solid-state lasers.

Lunch Break 12.05 to 13.30

Conference 8206

Session 6 will run concurrently with Session 14.

SESSION 6

Room: Multifunctional Hall.....Tues. 13.30 to 15.30

High-Power Laser Damage: UV Through IR II

Session Chairs: Roger Qiu, Lawrence Livermore National Lab. (USA); Xiaomin Zhang, China Academy of Engineering Physics (China)

In the activation of LFEX laser (1 ps, 10 kJ) system, we observed a heavy organic oil contamination in the compression chamber. The damage threshold (DT) of mirror dropped to $1/2 \sim 1/3$ of the original value. This contamination was observed only on the IAD (Ion beam Assisted Deposition) coated mirrors and gratings, and the oil frost was not observed on the mirror sample made with normal e-beam deposition. Contamination materials were identified as Paraffin-oil and DBP (Di-Butyl Phthalate). We made several efforts to reduce this contamination, and succeeded to keep DT to original value using silica gel in vacuum.

Founded in 1988, LULI is a French national scientific infrastructure dedicated to laser-generated hot and dense plasmas and applications. LULI develops and operates two large-scale laser facilities, LULI 2000 and ELFIE. Member of LASERLAB EUROPE, LULI is actively involved in the main high-peak-power laser projects in France and Europe. In this talk, an overview will be given on the LULI laser facilities and "Apollon 10PW", the French project which aims at producing 150 J, 10-15 fs pulses.

Laser performance enhancement cannot be accomplished without the advance in laser technologies and laser materials. High-energy ultra-intense laser requests specific laser and optical components in excellent quality, including high laser damage threshold, broad-spectral response, low transmitted or reflected wavefront deformation, etc. In this talk, a complete analysis will be given on the specifications of the key elements for building new-generation laser systems.

The properties of multi-shot laser-induced damage to glass substrate (fused silica and K9 glass) are investigated. 50 mm diameter, 5 mm thick test samples are manufactured by two different polishing processes. The test results suggest that: 1. Laser induced damage threshold is strongly correlated with subsurface damage. Samples polished by MRF have higher resistance to laser induced damage. 2. Acid etching does not improve the laser induced damage threshold of samples remarkably (an exception is a K9 glass sample polished by MRF). 3. The acid etched samples don't have distinct accumulation effect of multi-shot laser induced damage.

 SESSION 14

Room: Multifunctional Hall.....Tues. 13.30 to 15.15

Nonlinear Laser Crystal II

Session Chairs: **Zhanggui Hu,** Technical Institute of Physics and Chemistry (China); **Long Zhang,** Shanghai Institute of Optics and Fine Mechanics (China)

We developed high-quality single fluoride crystals by Czochralski technique. This activity covers different applications such as LIDAR, DIAL, high-resolution spectroscopy, metrology ,biology and optoelectronic. Among the crystals we can mention LiYF4, LiLuF4, BaY₂F₈ and LiGdF4 doped with rare earth ions (Ho³⁺, Tm³⁺, Pr³⁺ and Yb³⁺) to develop high efficiency tunable solid state laser in the near infrared (1 !m and 2 micron). Also we studied YLF crystal doped with Yb³⁺ and showed for the first time the development of solid state crycooler at 155 K temperature.

14.30: Czochralski growth and optical investigations of Er³⁺:GdTaO₄

Highly doped Er³⁺:GdTaO₄ crystal was grown by the Czochralski(CZ) method and its structure was determined by Rietveld Refinement to X-ray powder diffraction. Its absorption, photoluminescence spectra and fluorescence decay curve at room temperature were measured and studied. The absorption crosssections was evaluated and the Judd-Ofelt transition intensity parameters Ω (t=2, 4, 6) were fitted to its absorption spectrum. With parameters Ω t, the oscillator strengths, fluorescence branching ratios, transition probabilities and the lifetimes of Er³⁺:GdTaO₄ were calculated. The near-infrared and mid-infrared fluorescence properties were also discussed.

14.45: Optical and lasing properties of disordered Nd: SrLaGa₃O₇ crystal,

A disordered Nd:SrLaGa₃O₇ laser crystal was grown by the Czochralski method. It was found that the thermal conductivity increases with increasing temperature. The absorption band around 808 nm is about 8 nm, and the 4F3/2→4I11/2 luminescence bandwidth is nearly 14 nm. Judd-Ofelt analysis was carried out to calculate the fluorescence branching ratios and the stimulated emission cross section. In continuous laser experiment, the output power was obtained to be 3.88 W with a slope efficiency of 14.8%. To our knowledge, this is the highest cw power with Nd: SrLaGa₃O₇ as the gain medium and a laser-diode as the pump source.

Session 7 will run concurrently with Session 15.

SESSION 7

Room: Multifunctional Hall Tues. 15.50 to 18.50

Defects, Contamination, Polishing, and Surface Damage

Session Chairs: Takahisa Jitsuno, Osaka Univ. (Japan); Wanguo Zheng, China Academy of Engineering Physics (China)

15.50: Long pulsed laser-induced damage in optical materials

Long pulsed Nd:YAG laser with pulse width of few milliseconds induced damage in optical materials and components, including semiconductors, optical films on substrates, were investigated experimentally.

The experimentally measured LIDT on silicon is 127.2 J /cm² and 4.8 J /cm² for 1 ms and 10 ns pulsed laser irradiation. The damage morphologies in silicon and optical films induced by long pulsed laser were observed. The damage threshold on optical films decreases to a minimum value when the laser spot size increases. A cone-shaped cavity was observed in the substrate. The damage morphologies of anti-reflection and high-reflection coatings are different.

16.20: Mechanical polishing to improve uniformity of beam sampling

grating and its effects on laser-induced damage, Huanle Rao, Zhengkun Liu, Ying Liu, Shaojun Fu, Univ. of Science and Technology of China

In this paper, a mechanical polishing process was proposed to improve uniformity of the diffraction efficiency of beam sampling grating (BSG). The effect of this process on the laser induced damage threshold (LIDT) of BSG will also be studied. In the processing, CeO₂ was used to polish the local areas of grating in order to reduce their higher diffraction efficiency and achieve similar efficiency with the surrounding areas. The RMS of diffraction efficiency of BSG after mechanical polishing shows great reduction from 11.3% to 5.3%. LIDT measurement will be carried out at wavelength of 355nm.

This study was undertaken to evaluate the laser-induced damage of fused silica at 355 nm. The laser-damage threshold of fused silica samples was studied using laser-damage testing (355 nm, 6 ns). A new model, which improved the theory of defect-related induced damage, was proposed to describe the multiple-defect coupling effect of the nanosecond-pulsed laser-induced damage. The correlation between the damage probability and the damage threshold of the model were also reported.

16.50: Analysis of subsurface damage during fabrication process and its removal, Kun Xiao, Lei Bao, Wei Wang, Jianqiang Zhu, Shanghai Institute of

Subsurface damage appears inevitably during the shaping process, grinding process, polishing process and lapping process, which are essential in the production of defect-free optical components. In this study, we manage to detect the positions and depths of the SSDs via Total Internal Reflectance Microscopy. The lateral distribution of the SSDs is obtained. For both loose abrasive grinding, we found that rougher surface suggests deeper subsurface damage. The characteristics of subsurface damage during fabrication process are better known in this study, and we anticipate a final resolution to remove subsurface damage.

17.05: The influence of laser plasma effects on the characteristics of silicon surface damage, Jinghua Han, Weixing Fan, Sichuan Univ. (China);

Based on the laser plasma effects, the damage characters of silicon under high intensity nanosecond laser pulses have been investigated. The results show that laser plasma has the thermal effects, shock effects and spectral radiation effects, etc. These comprehensive effects combined together determinate the damage characters. The thermal effect of laser plasma makes the laser zone melting, vaporization and ionization; then the mixed mass will be pushed out by the effect of the shock wave. In this way, the pit can be formed at the laser irradiated area and the cooled ejected effluents are radial distributed. The silicon was melt at the bottom of the pit, meanwhile the incident laser was interfered with scattering light The temperature at the laser irradiated area is so high that not only the silicon was melt at the center, but also the heat spread like a wave that makes surface tension change and the periodic surface structures, like ripple, can be found after cooling.

SESSION 15

Room: Multifunctional Hall.....Tues. 15.35 to 18.20

Nonlinear Laser Crystal III

Session Chairs: Jian-Rong Qiu, South China Univ. of Technology (China); Yubai Pan, Shanghai Institute of Ceramics (China).

15.35: Optical and thermo-mechanical properties of pure and Yb-doped	
fluoride crystals for high-power laser systems (Invited Paper), Richard	
Moncorge, ENSICAEN (France)	78]

Optical and thermo-mechanical properties of pure and Yb doped fluoride crystals for high power laser systems

16.05: **Preparation and laser characterization of Cr**²⁺: **ZnSe mid-infrared laser crystals**, Yongjun Dong, Hao Zhang, Wei Chen, Yi Xu, Yanyan Li, Yuxin Leng, Shanghai Institute of Optics and Fine Mechanics (China) [8206-79] Cr²⁺: ZnSe single crystals used for the generation of 2~3µm mid-infrared laser were successfully grown by the temperature gradient method. The relationship between different growth process and crystal quality was investigated, and the crystal defects and spectra performance of the Cr²⁺: ZnSe single crystals were

crystal defects and spectra performance of the Cr²⁺: ZnSe single crystals were characterized. Using a widely tunable Tm:YAP laser as pumping sources, its laser performance was demonstrated.

KH₂PO₄ (KDP) and its deuterated analogue KD_xH_{2-x}PO₄ (DKDP) are currently the only nonlinear materials suitable as frequency converters and Pockel cells in high-power large-aperture laser systems. In the third harmonic generation (THG) of Nd:glass laser, DKDP is preferred used to substitute KDP crystal for its weak stimulated Raman scattering (SRS) effect. In this paper, DKDP crystals were grown by traditional technique from different deuterated solution. The crystal samples were selected to test the rocking curves, transmission spectra, Raman spectroscopy and the laser damage thresholds (LDT) and so on. We studied the impact of deuterium element on the structure and the properties of DKDP crystal by these tests.

Lead fluoride crystals doped with YbF₃, NaF- and KF-codoped were grown using the vertical Bridgman method. Influence of the codoping with Na+ and K+ ions on the distribution coefficients and photoluminescence spectra of the Yb ions has been studied.

16.50: Energy levels fitting and crystal-field calculations of Nd³⁺ doped in GYSGG crystal, Jinyun Gao, Qingli Zhang, Dunlu Sun, Shaotang Yin, Jianqiao Luo, Wenpeng Liu, Anhui Institute of Optics and Fine Mechanics

The single crystal Nd_{0.03}Gd_{0.93}Y_{2.04}Sc₂Ga₃O₁₂ (Nd³⁺:GYSGG) was grown by Czochralski method successfully, and its absorption spectra was analyzed in a wider spectral wavelength range at 7.6K and 300K, respectively. The free-ions and crystal-field parameters were fitted to the experimental energy levels in 7.6K and 300K with the root mean square deviation of 11.25 and 12.48 cm⁻¹, respectively. According to the crystal-field calculations, 116 levels of Nd³⁺ in 7.6K and 114 levels of Nd³⁺ in 300K were assigned. Finally, the fitting results of free-ions and crystal-field parameters are compared with those already reported for Nd³⁺:GSGG and Nd³⁺:YSAG.

17.05: Generation and mechanism discussion of multiwavelength garnet crystal lasers, Haohai Yu, Kui Wu, Zhongben Pan, Huaijin Zhang, Zhengping

We report multi-wavelength lasers at about 1.06 μm with the three garnet laser crystals and discuss their generating mechanisms, which include frequency selector by a saturable absorber, generations by multi-emission centers and stark splitting. We also proposed that the multi-wavelength lasers should have applications in optical communications, optical instrumentation, probe-pump experiments, optical beating, remote sensing, and coherent terahertz generation.

Compared to KDP crystal, DKDP has low laser-induced damage threshold,higher light transmittance,lower half-wave voltage and bigger electro-optical coefficient. With the development of ICF project,the requierment of output energy of DKDP crystal is imroving,so we carried out some related experiments in present work on the fourth harmonic frequency generation of DKDP crystal.

Session 7 will run concurrently with Session 15.

SESSION 7 (Continued)

Room: Multifunctional Hall.....Tues. 15.50 to 18.50

Laser Calorimeter was chosen to measure the weak absorption of HfO₂ film.Three different wavelength laser was utilized, and each measurement was taken 20 times. Decreasing of absorption was recorded, and the data was carefully treated. Different cleaning methods were taken use of to compare with Laser cleaning. A Laser cleaning model was established.

To study Light intensity modulations caused by opaque obstacles, particles were sputter deposited on the input surface and irradiated with a 6.8 ns laser beam at 355nm. The results show that the LIDT of the fused silica decended to 7 J/cm² form 12 J/cm², and descend exponential with the sizes of the contamination particles. The relation between the depth and fluences is linear to the same contamination size. The experiments are modeled by calculating the light intensity distribution behind an obscuration by using of fresnel diffraction theory. The comparisons between calculated light intensity distribution and damage pattern show good agreement.

17.50: Study of dust-pollution-induced laser damage on fused silica

18.05: Study on mechanisms of HF solution improving damage properties of fused silica subsurface cracks, Fengrui Wang, China Academy of

Fused silica optic was etched by HF solution, the morphology and damage properties of micro subsurface cracks were studied. Experimental and theoretical results show that heat absorption of inclusions in cracks, and light field intensification caused by inclusions and the crack are critical roles which induces the low damage threshold. Etching with HF solution can eliminate the inclusions effectively, the cracks are passivated and transformed into different morphologies, and after the etching process, heat absorption and light intensification caused by cracks decreased dramatically, and the crack's damage threshold increased more than one time.

18.20: Research of removing polishing powders from BK7 substrates by ultrasonic cleaning method, Tao Ding, Xinbin Chen, Zhengxiang Shen, Bin Ma,

Jinlong Zhang, Hongfei Jiao, Zhanshan Wang, Tongji Univ. (China) [8206-45]

The cleaning process of optical substrates plays an important role during the manufacture of high-power laser coatings. In this study, the polishing powders such as cerium dioxide were deposited on the cleaning substrates, and the ultrasonic cleaning method was employed to remove the particles. During this process, the ultrasonic frequencies were varied from 40KHz to 170KHz to detect the function between the removal efficiency and the ultrasonic frequency. Specifically, it was also found the PH value of the solvent have much influence to the cleaning efficiency.

18.35: Reduction of the 355-nm laser-induced damage initiators by

The laser damage resistance was improved more than 2.2-fold by removing the subsurface defects in fused silica. HF/NH4F etching and magneticrheological finishing were used to reduce the subsurface defects. The effect of the subsurface defects removal on laser damage resistance was characterized by measuring the laser-induced damage threshold (LIDT) at 355nm. Results show that the crack number density of the final treated sample decreased from ~103 to <10 cm⁻², and the surface-LIDT enhanced from 13.2 to 30 J/cm² compared with the un-treated sample.

SESSION 15 (Continued)

Room: Multifunctional Hall.....Tues. 15.35 to 18.20

TW/cm². One SHG and two OPCPA experiments were excuted to characterize the nonlinear optical properties of YCOB crytals and the quality of the crystals. The results shown that YCOB had good performance in OPCPA application, especially with low content of parameter florescence. Combined with good NLO performance and possibility to grow large size crystals, YCOB crystal was a good choice for high power OPCPA applications.

18.05: Spectroscopic properties of Yb-doped Ca_{1-x}Sr_xF₂ laser crystals by γ -rays irradiation, Yeqing Wu, Shanghai Institute of Ceramics (China) . [8206-87]

In this paper, the spectroscopic properties of Yb:Ca_{0.5}Sr_{0.5}F₂, Yb, Na:Ca_{0.5}Sr_{0.5}F₂ disordered crystals and Yb:CaF₂, Yb, Na:CaF₂ single crystals were studied after γ -rays irradiation. These crystals were grown by the Bridgman technique. Colour centres and Yb²⁺ formed in these crystals by γ -rays irradiation. The influence of codoping with Na+ on the spectra has been studied. The results showed that Na+ codoping with Yb³⁺ as charge compensators can suppress the deoxidization of Yb³⁺ to Yb²⁺. The spectroscopic properties of these crystals were also studied after heating samples.

Closing Remarks Tues. 18.50 to 19.00

Wednesday 9 November

SIOM Tour and Excursion to Zhouzhuang Wed. 08.00 to 17.00

The conference organizers will be leading a brief tour of the SIOM laser facility followed by an excursion to Zhouzhuang, an ancient water town short-listed as a possible UNESCO World Cultural Heritage Site. Attendees can register for this event at the registration desk for an additional \$40 US.

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Notes





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